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74LCX543 Low Voltage Octal Registered Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX543 is a non-inverting octal transceiver containing two sets of D-type registers for temporary storage of data flowing in either direction. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The LCX543 is designed for low voltage (2.5V or 3.3V) $\rm V_{CC}$ applications with capability of interfacing to a 5V signal environment.

The LCX543 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V 3.6V V_{CC} specifications provided
- **T** 7.0 ns t_{PD} max (V_{CC} = 3.3V), 10 μ A I_{CC} max
- Power down high impedance inputs and outputs

May 1995

Revised March 2001

- Supports live insertion/withdrawal (Note 1)
- \pm 24 mA Output Drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74LCX543WM	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LCX543MSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCX543MTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



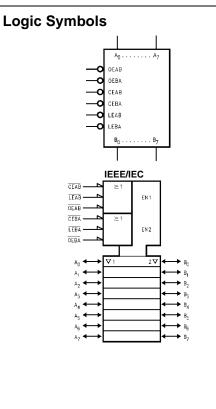
Pin Descriptions

Pin Names	Description
OEAB	A-to-B Output Enable Input (Active LOW)
OEBA	B-to-A Output Enable Input (Active LOW)
CEAB	A-to-B Enable Input (Active LOW)
CEBA	B-to-A Enable Input (Active LOW)
LEAB	A-to-B Latch Enable Input (Active LOW)
LEBA	B-to-A Latch Enable Input (Active LOW)
A ₀ A ₇	A-to-B Data Inputs or
	B-to-A 3-STATE Outputs
B ₀ –B ₇	B-to-A Data Inputs or
	A-to-B 3-STATE Outputs

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Data I/O Control Table

	Inputs		Latab Otatura	Outrust Duffing	
CEAB	LEAB	OEAB	Latch Status	Output Buffers	
Н	Х	Х	Latched	High Z	
Х	н	Х	Latched	—	
L	L	Х	Transparent	—	
х	Х	н	—	High Z	
L	Х	L	—	Driving	

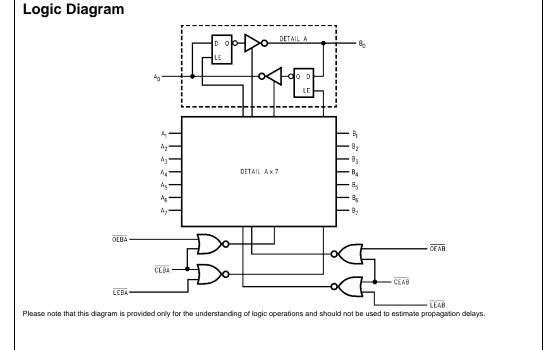
H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

A-to-B data flow shown; B-to-A flow control is the same, except using CEBA, LEBA and $\overline{\text{OEBA}}$

Functional Description

The LCX543 contains two sets of eight D-type latches, with separate input and output controls for each set. For data flow from A to B, for example, the A-to-B Enable (CEAB) input must be LOW in order to enter data from A₀–A₇ or take data from B₀–B₇, as indicated in the Data I/O Control Table. With CEAB LOW, a LOW signal on the A-to-B Latch Enable (LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the LEAB signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With CEAB and OEAB both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the CEBA, LEBA and OEAB inputs.



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Symbol	Parameter	Value	Con	ditions		Units
V _{CC}	Supply Voltage	-0.5 to +7.0				V
VI	DC Input Voltage	-0.5 to +7.0				V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE			V
		-0.5 to V _{CC} + 0.5	Output in HIGH or L	OW State	(Note 3)	v
lık	DC Input Diode Current	-50	V _I < GND			mA
I _{OK}	DC Output Diode Current	-50	V _O < GND			mA
		+50	$V_{O} > V_{CC}$			mA
lo	DC Output Source/Sink Current	±50				mA
I _{CC}	DC Supply Current per Supply Pin	±100				mA
I _{GND}	DC Ground Current per Ground Pin	±100				mA
T _{STG}	Storage Temperature	-65 to +150				°C
Recoi Symbol	mmended Operating Co	nditions (Note 4	4)	Min	Max	Units
V _{CC}	Supply Voltage		Operating	2.0	3.6	V
			Data Retention	1.5	3.6	v
VI	Input Voltage	nput Voltage 0 5.5				
Vo	Output Voltage		HIGH or LOW State	0	V _{CC}	V
			3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current		$V_{CC} = 3.0V - 3.6V$		±24	
			$V_{CC} = 2.7V - 3.0V$		±12	mA
			VCC - 2.7 V 0.0 V		± • -	

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Symbol	Parameter		Min	Max	Units	
V _{CC}	Supply Voltage	Operating	2.0	3.6	V	
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V	
		3-STATE	0	5.5	v	
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24		
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA	
		$V_{CC}=2.3V-2.7V$		±8		
T _A	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$		0	10	ns/V	

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: ${\rm I}_{\rm O}$ Absolute Maximum Rating must be observed.

Note 4: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Gymbol		Conditions	(V)	Min	Max	onita
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	v
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		•
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		I _{OH} = -24 mA	3.0	2.2		•
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 8mA	2.3		0.6	•
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	•
		I _{OL} = 24 mA	3.0		0.55	
l _l	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ
I _{OZ}	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH}$ or V_{IL}	2.5 - 5.0		±0.0	μΑ
OFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0		10	μΑ

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DC Electrical Characteristics (Continued)

V_{cc} $T_A = -40^{\circ}C$ to $+85^{\circ}C$ Symbol Parameter Conditions Units (V) Min Max Quiescent Supply Current $V_I = V_{CC}$ or GND 2.3 - 3.610 I_{CC} μΑ $3.6V \le V_I, V_O \le 5.5V$ (Note 5) 2.3 - 3.6 ±10 500 $V_{IH} = V_{CC} - 0.6V$ 2.3 - 3.6 ΔI_{CC} Increase in I_{CC} per Input μΑ

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40^\circ$ C to $+85^\circ$ C, $R_L = 500\Omega$						
		$V_{CC}=3.3V\pm0.3V$ $C_L=50\ pF$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
Symbol	Farameter							
		Min	Max	Min	Max	Min	Max	1
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	
t _{PLH}	A _n to B _n or B _n to A _n	1.5	7.0	1.5	8.0	1.5	8.4	ns
t _{PHL}	Propagation Delay	1.5	8.5	1.5	9.5	1.5	10.5	ns
t _{PLH}	LEBA to A _n or LEAB to B _n	1.5	8.5	1.5	9.5	1.5	10.5	
t _{PZL}	Output Enable Time	1.5	9.0	1.5	10.0	1.5	11.0	
t _{PZH}	OEBA or OEAB to An or Bn	1.5	9.0	1.5	10.0	1.5	11.0	ns
	CEBA or CEAB to An or Bn							
t _{PLZ}	Output Disable Time	1.5	7.0	1.5	7.5	1.5	8.4	
t _{PHZ}	OEBA or OEAB to An or Bn	1.5	7.0	1.5	7.5	1.5	8.4	ns
	CEBA or CEAB to An or Bn							
t _S	Setup Time, HIGH or LOW Data to LEXX	2.5		2.5		4.0		ns
t _H	Hold Time, HIGH or LOW Data to LEXX	1.5		1.5		2.0		ns
t _W	Pulse Width, Latch Enable, LOW	3.3		3.3		3.3		ns
toshl	Output to Output Skew		1.0					ns
t _{OSLH}	(Note 6)		1.0					115

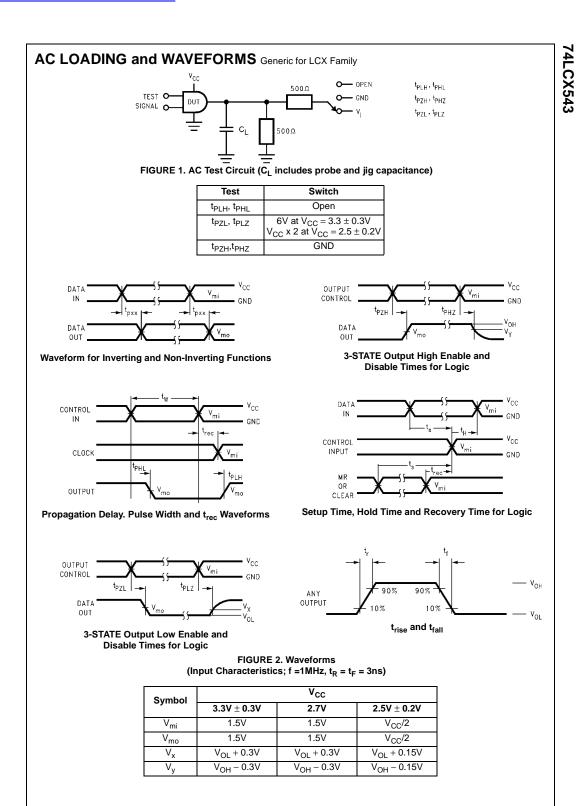
Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
			(V)	Typical	
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L=30 \text{ pF}, \text{ V}_{IH}=2.5 \text{V}, \text{ V}_{IL}=0 \text{V}$	2.5	-0.6	v

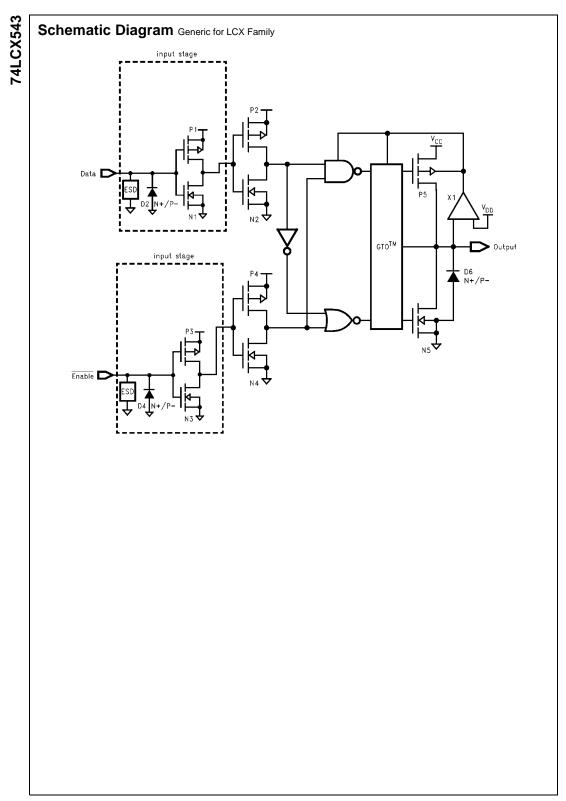
Capacitance

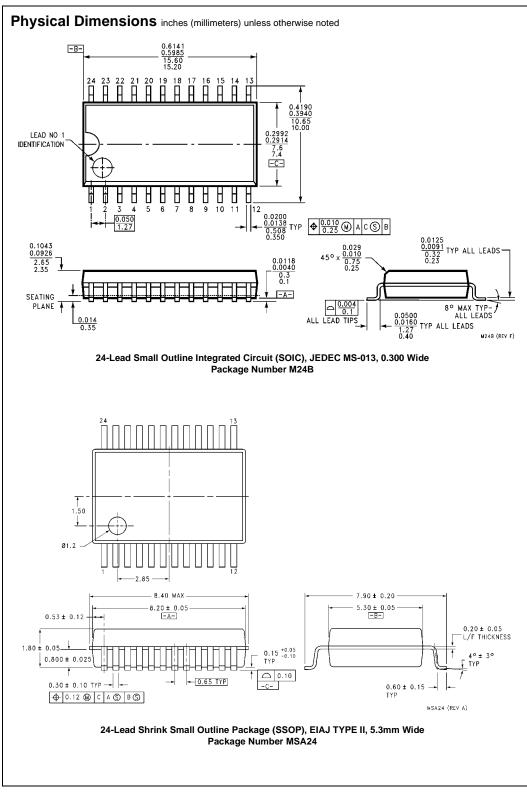
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	25	pF



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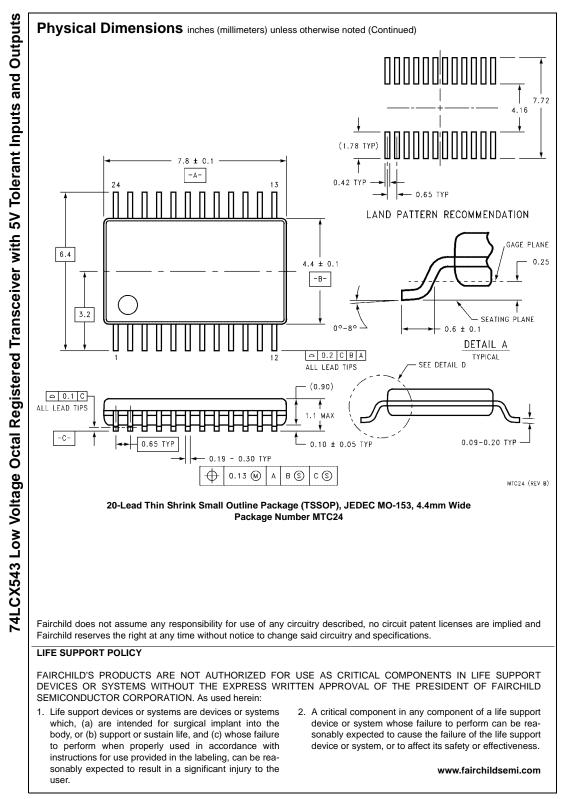
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